

BCR12CM-16LB

800V - 12A - Triac

Medium Power Use

R07DS0976EJ0300 Rev.3.00 Feb. 1, 2019

Features

I_{T (RMS)}: 12 A
 V_{DRM}: 800 V

• I_{FGTI}, I_{RGTI}, I_{RGT III}: 30 mA

• Tj: 150°C

• Non-insulated Type

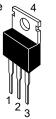
• Planar Passivation Type

Outline



RENESAS Package code: PRSS0004AT-A (Package name: TO-220ABA)

Ordering code #BH0





1. T₁ Terminal

2. T₂ Terminal3. Gate Terminal

4. T₂ Terminal

Application

Power supply, motor control, heater control and other general purpose AC control applications.

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
		16	
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	800	V
Non-repetitive peak off-state voltage ^{Note1}	V_{DSM}	960	V

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T (RMS)}	12	Α	Commercial frequency, sine full wave 360° conduction, Tc = 123°C ^{Note3}
Surge on-state current	I _{TSM}	120	Α	60 Hz sinewave 1 full cycle, peak value, non-repetitive
I ² t for fusion	l ² t	60	A ² s	Value corresponding to 1 cycle of half wave 60 Hz, surge on-state current
Peak gate power dissipation	P _{GM}	5	W	
Average gate power dissipation	P _G (AV)	0.5	W	
Peak gate voltage	V _{GM}	10	V	
Peak gate current	l _{GM}	2	Α	
Junction Temperature	Tj	-40 to +150	°C	
Storage temperature	Tstg	-40 to +150	°C	

Electrical Characteristics

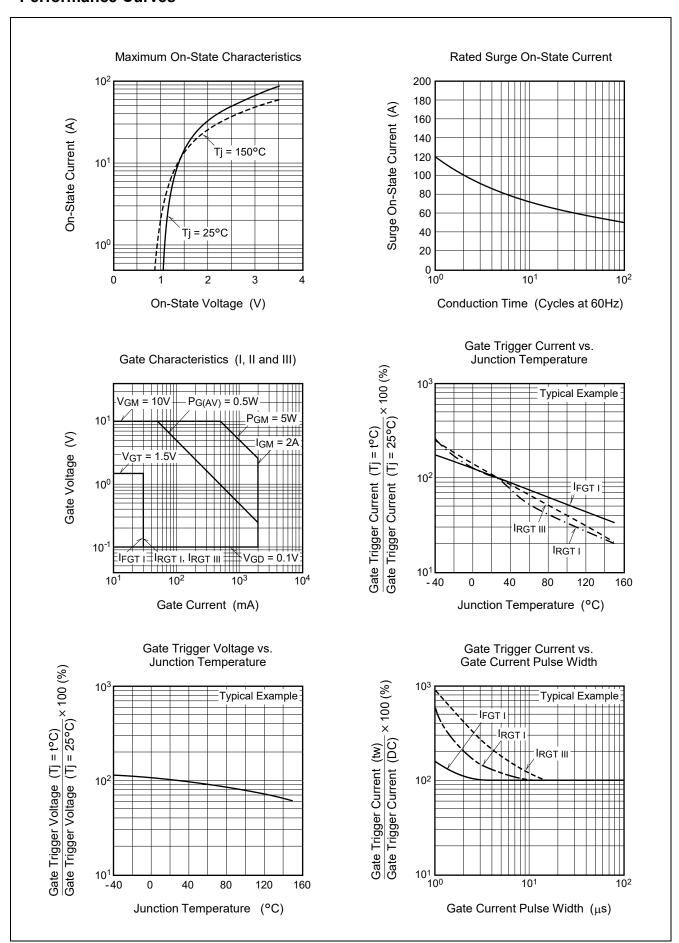
Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state cur	rent	I _{DRM}	_	_	2.0	mA	Tj = 150°C, V _{DRM} applied
On-state voltage		V _{TM}	_	_	1.6	V	Tc = 25°C, I _{TM} = 20 A, instantaneous measurement
Gate trigger voltageNote2	I	V _{FGTI}	_	_	1.5	V	Tj = 25°C, V_D = 6 V, R_L = 6 Ω,
	II	V_{RGTI}	_	_	1.5	V	$R_G = 330 \Omega$
	III	V _{RGTIII}	_	_	1.5	V	
Gate trigger currentNote2	I	I _{FGTI}	_	_	30	mA	Tj = 25°C, V_D = 6 V, R_L = 6 Ω,
	II	I _{RGTI}	_	_	30	mA	$R_G = 330 \Omega$
	III	I _{RGTIII}	_	_	30	mA	
Gate non-trigger voltage		V_{GD}	0.2	_	_	V	Tj = 125°C, V _D = 1/2 V _{DRM}
			0.1	_	_	V	Tj = 150°C, V _D = 1/2 V _{DRM}
Thermal resistance		R _{th (j-c)}			1.8	°C/W	Junction to case ^{Note3 Note4}
Critical-rate of rise of off-state		(dv/dt)c	10	_	_	V/μs	Tj = 125°C
commutation voltage ^{Note5}			1	_	_	V/μs	Tj = 150°C

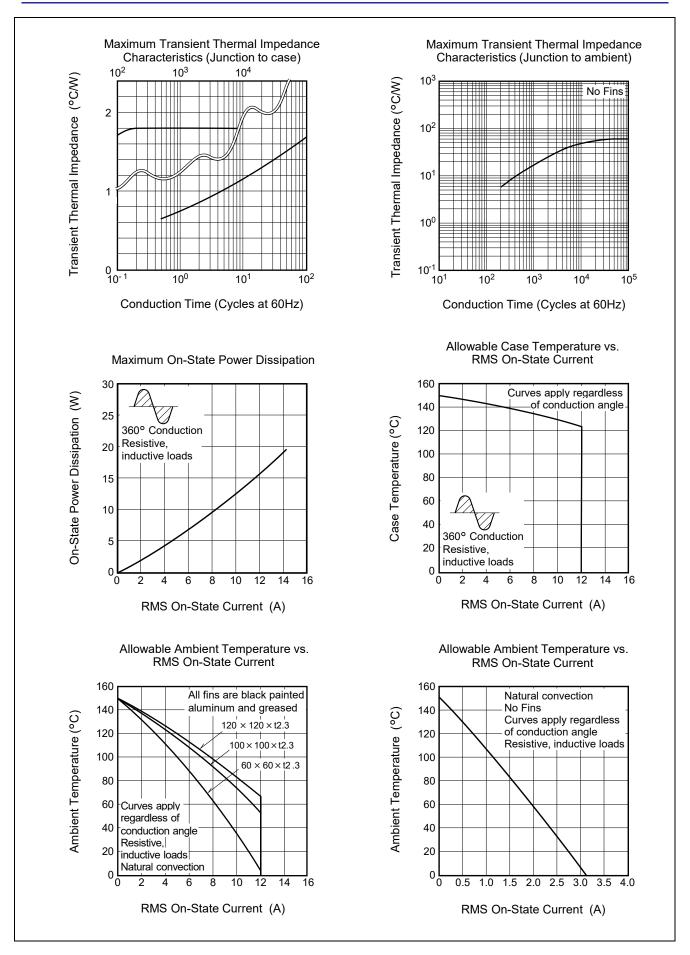
Notes: 1. Gate open.

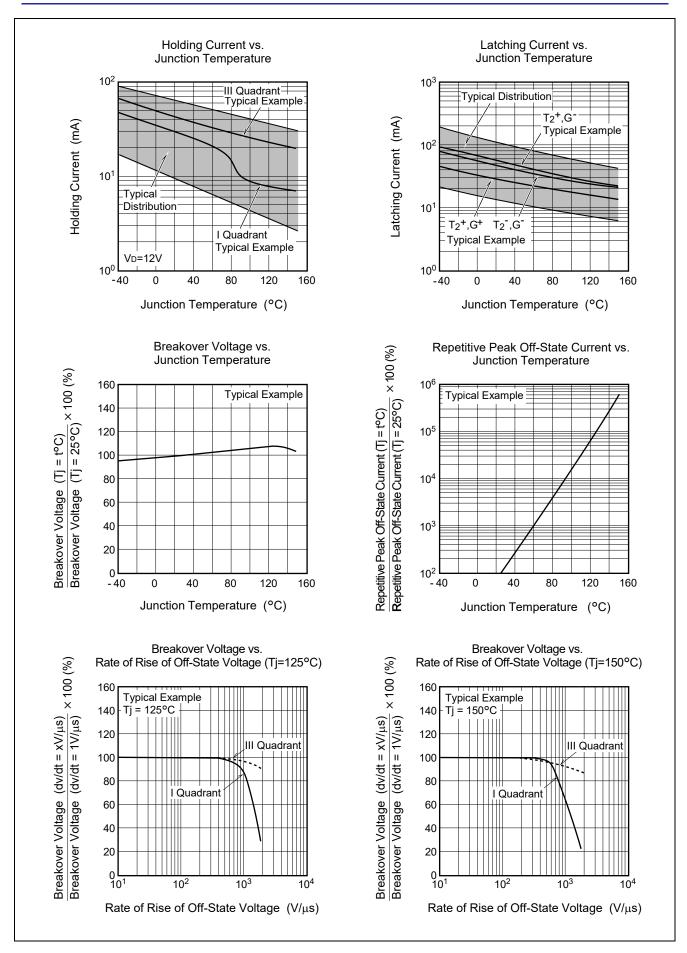
- 2. Measurement using the gate trigger characteristics measurement circuit.
- 3. Case temperature is measured at the T_2 tab 1.5 mm away from the molded case.
- 4. The contact thermal resistance $R_{\text{th(c-f)}}$ in case of greasing is 1.0°C /W.
- 5. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.

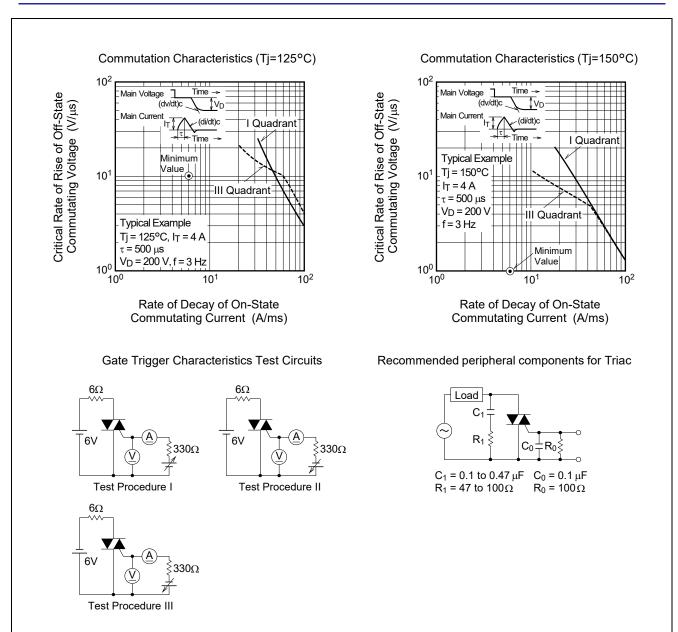
Test conditions	Commutating voltage and current waveforms (inductive load)
 Junction temperature Tj = 125°C/150°C Rate of decay of on-state commutating current (di/dt)c = -6 A/ms Peak off-state voltage V_D = 400 V 	Supply Voltage Main Current Main Voltage (di/dt)c Time Main Voltage (dv/dt)c V _D

Performance Curves



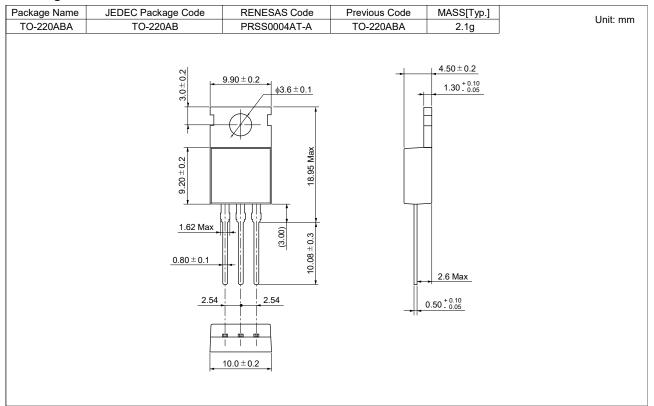




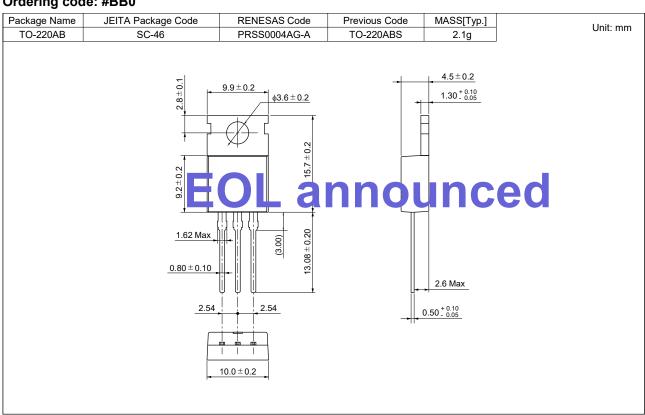


Package Dimensions

Ordering code: #BH0



Ordering code: #BB0



Ordering Information

Orderable Part Number	Package	Quantity Note6	Remark	Status
BCR12CM-16LB#BH0	TO-220ABA	50 pcs./ tube	Straight type	Mass Production
BCR12CM-16LB#BB0	TO-220ABS	50 pcs./ tube	Straight type	EOL announced

Notes: 6. Please confirm the specification about the shipping in detail.

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